NSN 5961-00-912-1676

Transistor - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.546 inches

Overall Diameter:

1.281 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Internal Junction Configuration:

Npn

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

250.0 breakdown voltage, collector-to-emitter, base open and 25.0 breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between 5.00 amperes source cutoff current and 7.50 amperes source cutoff current

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

80131-release2653 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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